



Switch mode **Full Plastic Single Ultra-fast Power Rectifiers**

Designed for use in switching power supplies, inverters and as free-wheeling diodes. These state-of-the-art devices have the following

Features

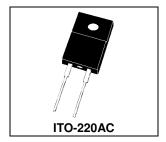
- *Low T_{RR}
- *High Surge Capacity
- *Low Power Loss, High efficiency
- *175℃ Operating Junction Temperature
- *Low Forward Voltage, High Frequency
- *High-Switching Speed Recovery Time
- * Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O
- *Pb free
- * In compliance with EU RoHs directives

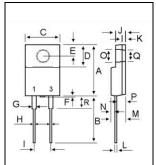




ULTRA FAST RECTIFIERS

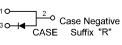
8 AMPERES 600 VOLTS





DIM	MILLIMETERS		
	MIN	MAX	
Α	14.80	16.10	
В	12.65	14.40	
С	9.70	10.36	
D	4.60	6.80	
Ε	2.50	3.50	
F		2.00	
G	0.90	1.45	
Н	0.50	0.90	
- 1	4.80	5.40	
J	2.34	3.30	
K	0.55	1.30	
L	0.36	0.80	
M	4.20	4.90	
Ν	1.10	1.80	
0	2.90	3.50	
Р	2.30	3.15	
Q	2.90	3.50	
R	2.80	4.85	





MAXIMUM RATINGS

Characteristic	Symbol	UFEF08A60	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	600	V
RMS Reverse Voltage	V _{R(RMS)}	420	V
Average Rectifier Forward Current	I _{F(AV)}	8.0	А
Peak Repetitive Forward Current (Rate V _R , Square Wave, 20kHz)	I _{FM}	8.0	А
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions half-wave, single phase, 60Hz)	I _{FSM}	100	А
Operating and Storage Junction Temperature Range	T_J , T_stg	-65 to +175	S

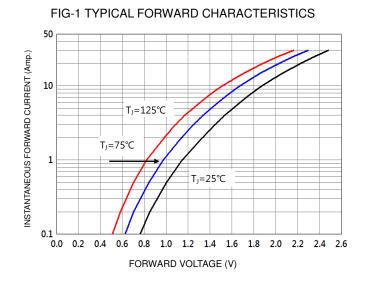
THERMAL RESISTANCES

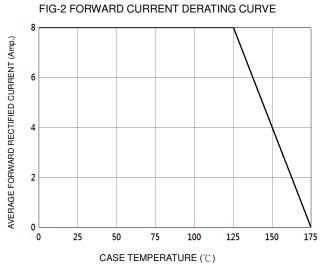
Typical Thermal Resistance junction to case	$R_{ hetajc}$	4.2	°C/w
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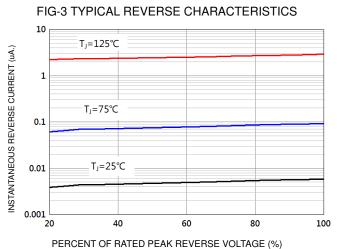
FLECTRICAL CHARACTERISTICS

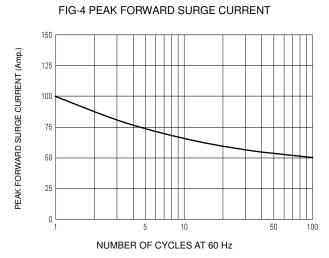
LLECTHICAL CHARACTERISTICS							
Characteristic	Symbol	Min.	Тур.	Max.	Unit		
Maximum Instantaneous Forward Voltage ($I_F = 8 \text{ Amp } T_C = 25^{\circ}C$) ($I_F = 8 \text{ Amp } T_C = 125^{\circ}C$)	V _F	1 1	1.85 1.50	2.2	٧		
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C = 25^{\circ}C$) (Rated DC Voltage, $T_C = 125^{\circ}C$)	I _R	1 -	0.02 5	25 	uA		
Reverse Recovery Time ($I_F = 0.5 \text{ A}$, $I_R = 1.0$, $I_{rr} = 0.25 \text{ A}$)	T _{rr}		22	25	ns		

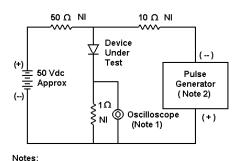


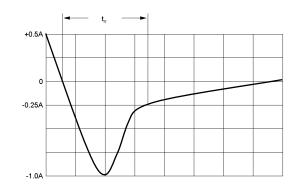












1. Rise Time = 7 ns max. Input Impedance =1 M Ω , 22 pF 2. Rise Time = 10 ns max. Input Impedance = 50 Ω

Set time base for 10/20 ns/cm FIG-5 Reverse Recovery Time Characteristic and Test Circuit Diagram



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